

#### *Data Sheet December 14, 2007*

# **Boost + LDO + V<sub>ON</sub> Slice + V<sub>COM</sub>**

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The ISL97646 represents an integrated DC/DC regulator for monitor and notebook applications with screen sizes up to 20". The device integrates a boost converter for generating  $A<sub>VDD</sub>$ , a  $V<sub>ON</sub>$  slice circuit, an integrated logic LDO and a high performance  $V_{COM}$  amplifier.

The boost converter features a 2.6A FET and has user programmable soft-start and compensation. With efficiencies up to 92%, the  $A_{VDD}$  is user selectable from 7V to 20V.

The logic LDO includes a 350mA FET for driving the low voltage needed by the external digital circuitry.

The  $V_{ON}$  slice circuit can control gate voltages up to 30V. High and low levels are programmable, as well as discharge rate and timing.

The integrated  $V_{COM}$  features high speed and drive capability. With 30MHz bandwidth and 50V/us slew rate, the V<sub>COM</sub> amplifier is capable of driving 400mA peaks, and 100mA continuous output current.

## *Pinout*



## *Features*

- 2.7V to 5.5V Input
- 2.6A Integrated Boost for Up to 20V A<sub>VDD</sub>
- Integrated  $V_{ON}$  Slice
- 350mA V<sub>LOGIC</sub> LDO
	- 2.5V, 2.85V, 3.3V Output Voltage Selectable
- $\cdot$  600kHz/1.2MHz fs
- V<sub>COM</sub> Amplifier
	- 30MHz BW
	- 50V/µs SR
	- 400mA Peak Output Current
- UV and OT Protection
- 24 Ld 4x4 QFN
- Pb-Free (RoHS Compliant)

## *Applications*

- LCD Monitors (15"+)
- Notebook Display (up to 16")

## *Ordering Information*



[\\*Please refer to TB347 for details on reel specifications.](http://www.intersil.com/data/tb/tb347.pdf)

NOTE: These Intersil Pb-free plastic packaged products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate PLUS ANNEAL - e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

# *Pin Descriptions*



#### Absolute Maximum Ratings **Thermal Information**



## **Recommended Operating Conditions**





*CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.*

NOTES:

<span id="page-2-0"></span>1. θJA is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.

<span id="page-2-1"></span>2. For  $\theta_{JC}$ , the "case temp" location is the center of the exposed metal pad on the package underside.





#### **Electrical Specifications**  $V_{IN1} = V_{IN2} = ENABLE = 5V$ , VDD1 = VDD2 = 14V, VGH = 25V, AVDD = 10V, T<sub>A</sub> = -40°C to +85°C Unless Otherwise Noted. **(Continued)**



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NOTES:

<span id="page-4-0"></span>3. Nominal discharge current =  $300/(RE + 5kΩ)$ .

<span id="page-4-1"></span>4. Nominal delay time = 4000\*CE.

# I *Typical Performance Curves*













FIGURE 3. LINE REGULATION A<sub>VDD</sub> vs V<sub>IN</sub> FIGURE 4. BOOST CONVERTER TRANSIENT RESPONSE









# *Block Diagram*



<span id="page-7-0"></span>**FIGURE 13. ISL97646 BLOCK DIAGRAM**

# *Typical Application Diagram*



# *Applications Information*

The ISL97646 provides a complete power solution for TFT LCD applications. The system consists of one boost converter to generate  $A_{VDD}$  voltage for column drivers, one logic LDO regulator to provide voltage to logic circuit in the LCD panel, one integrated  $V_{COM}$  buffer which can provide up to 400mA peak current. This part also integrates a Gate Pulse Modulator circuit that can help to optimize the picture quality.

# *Enable Control*

When enable pin is pulling down, the ISL97646 is shut down reducing the supply current to <10µA. When the voltage at enable pin reaches 2.2V, the ISL97646 is on.

# *Boost Converter*

## *Frequency Selection*

The ISL97646 switching frequency can be user selected to operate at either constant 650kHz or 1.2MHz. Lower switching frequency can save power dissipation, while higher switching frequency can allow smaller external components like inductor and output capacitors, etc. Connecting FREQ pin to ground sets the PWM switching frequency to 650MHz, or connecting FREQ pin to  $V_{IN}$  for 1.2MHz.

## *Soft-Start*

The soft-start is provided by an internal 2.5µA current source to charge the external soft start capacitor. The ISL97646 ramps up current limit from 0A up to full value, as the voltage at SS pin ramps from 0V to 1.2V. Hence the soft-start time is 4.8ms when the soft-start capacitor is 10nF, 22.6ms for 47nF and 48ms for 100nF.

## *Operation*

The boost converter is a current mode PWM converter operating at either a 650kHz or 1.2MHz. It can operate in both discontinuous conduction mode (DCM) at light load and continuous mode (CCM). In continuous current mode, current flows continuously in the inductor during the entire switching cycle in steady state operation. The voltage conversion ratio in continuous current mode is given by:

$$
\frac{V_{\text{BOOST}}}{V_{\text{IN}}} = \frac{1}{1 - D} \tag{Eq. 1}
$$

Where D is the duty cycle of the switching MOSFET.

Figure [13](#page-7-0) shows the block diagram of the boost regulator. It uses a summing amplifier architecture consisting of gm stages for voltage feedback, current feedback and slope compensation. A comparator looks at the peak inductor current cycle by cycle and terminates the PWM cycle if the current limit is reached.

An external resistor divider is required to divide the output voltage down to the nominal reference voltage. Current drawn by the resistor network should be limited to maintain the overall converter efficiency. The maximum value of the resistor network is limited by the feedback input bias current and the potential for noise being coupled into the feedback pin. A resistor network in the order of 60kΩ is recommended. The boost converter output voltage is determined by Equation [2:](#page-9-1)

$$
V_{\text{BOOST}} = \frac{R_1 + R_2}{R_2} \times V_{\text{FB}}
$$
 (Eq. 2)

The current through the MOSFET is limited to  $2.6A<sub>PFAK</sub>$ .

This restricts the maximum output current (average) based on the Equation [3](#page-9-2):

<span id="page-9-2"></span>
$$
I_{OMAX} = \left(I_{LMT} - \frac{\Delta I_L}{2}\right) \times \frac{V_{IN}}{V_O}
$$
 (EQ. 3)

Where  $\Delta I_1$  is peak to peak inductor ripple current, and is set by:

$$
\Delta I_{L} = \frac{V_{IN}}{L} \times \frac{D}{f_{s}}
$$
 (EQ. 4)

where  $f_S$  is the switching frequency (650kHz or 1.2MHz).

Table [2](#page-9-0) gives typical values (margins are considered 10%, 3%, 20%, 10% and 15% on  $V_{IN}$ ,  $V_{O}$ , L, f<sub>S</sub> and  $I_{OMAX}$ ).

## *Capacitor*

An input capacitor is used to suppress the voltage ripple injected into the boost converter. The ceramic capacitor with capacitance larger than 10µF is recommended. The voltage rating of input capacitor should be larger than the maximum input voltage. Some capacitors are recommended in Table 1 for input capacitor.

#### **TABLE 1. BOOST CONVERTER INPUT CAPACITOR RECOMMENDATION**



#### <span id="page-9-1"></span>**TABLE 2. MAXIMUM OUTPUT CURRENT CALCULATION**

<span id="page-9-0"></span>

## *Inductor*

The boost inductor is a critical part which influences the output voltage ripple, transient response, and efficiency. Values of 3.3µH to 10µH are used to match the internal slope compensation. The inductor must be able to handle the following average and peak current:

$$
I_{\text{LAVG}} = \frac{I_{\text{O}}}{1 - \text{D}}
$$
\n
$$
I_{\text{LPK}} = I_{\text{LAVG}} + \frac{\Delta I_{\text{L}}}{2}
$$
\n(EQ. 5)

Some inductors are recommended in Table 3.

**TABLE 3. BOOST INDUCTOR RECOMMENDATION**

<b>INDUCTOR</b>	<b>DIMENSIONS</b> (mm)	<b>MFG</b>	<b>PART NUMBER</b>
$6.8\mu H/3APFAK$	7.3x6.8x3.2	TDK	RLF7030T-6R8N3R0
10µH/4A <sub>PEAK</sub>	8.3x8.3x4.5	Sumida	CDR8D43-100NC
5.2µH/4.55A <sub>PEAK</sub> 10x10.1x3.8		Cooper <b>Bussmann</b>	CD1-5R2

## *Rectifier Diode*

A high-speed diode is necessary due to the high switching frequency. Schottky diodes are recommended because of their fast recovery time and low forward voltage. The reverse voltage rating of this diode should be higher than the maximum output voltage. The rectifier diode must meet the output current and peak inductor current requirements. Table [4](#page-10-1) lists some recommendations for boost converter diode.

<span id="page-10-1"></span>**TABLE 4. BOOST CONVERTER RECTIFIER DIODE RECOMMENDATION**

<b>DIODE</b>	V <sub>R</sub> /I <sub>AVG</sub> RATING	<b>PACKAGE</b>	<b>MFG</b>
SS <sub>23</sub>	30V/2A	<b>SMB</b>	Fairchild Semiconductor
MBRS340	40V/3A	<b>SMC</b>	International Rectifier
<b>SL23</b>	30V/2A	<b>SMB</b>	Vishay Semiconductor

# *Output Capacitor*

The output capacitor supplies the load directly and reduces the ripple voltage at the output. Output ripple voltage consists of two components: the voltage drop due to the inductor ripple current flowing through the ESR of output capacitor, and the charging and discharging of the output capacitor.

$$
V_{RIPPLE} = I_{LPK} \times ESR + \frac{V_O - V_{IN}}{V_O} \times \frac{I_O}{C_{OUT}} \times \frac{1}{f_s}
$$
 (EQ. 6)

For low ESR ceramic capacitors, the output ripple is dominated by the charging and discharging of the output capacitor. The voltage rating of the output capacitor should be greater than the maximum output voltage.

NOTE: Capacitors have a voltage coefficient that makes their effective capacitance drop as the voltage across then increases.  $C<sub>OUT</sub>$  in Equation [6](#page-10-3) above assumes the effective value of the capacitor at a particular voltage and not the manufacturer's stated value, measured at zero volts.

Table [5](#page-10-2) lists some selections of output capacitors.

<span id="page-10-2"></span>



## *Compensation*

The boost converter of ISL97646 can be compensated by a RC network connected from the CM1 pin to ground. 4.7nF and 10k RC network is used in the demo board. The larger value resistor and lower value capacitor can lower the transient overshoot, however, at the expense of stability of the loop.

## *Cascaded MOSFET Application*

A 20V N-Channel MOSFET is integrated in the boost regulator. For the applications where the output voltage is greater than 20V, an external cascaded MOSFET is needed, as shown in Figure [15.](#page-10-0) The voltage rating of the external MOSFET should be greater than  $A<sub>VDD</sub>$ .



<span id="page-10-0"></span>**FIGURE 15. CASCADED MOSFET TOPOLOGY FOR HIGH OUTPUT VOLTAGE APPLICATIONS**

# *Linear-Regulator (LDO)*

<span id="page-10-3"></span>The ISL97646 includes a LDO with adjustable output, and it can supply current up to 350mA. The output voltage is adjusted by connection of ADJ pin. When ADJ pin is connected to ground, the output voltage is set to 3.3V; when ADJ pin is floating, the output voltage is set to 2.85V, and when ADJ pin is connected to LDO\_OUT pin, the output voltage is set to 2.5V.

The efficiency of LDO is depended on the difference between input voltage and output voltage, as well as the output current:

$$
\eta(\%) = (V_{1N1} - V_{LDO\_OUT}) \times I_{LDO\_OUT} \times 100\% \tag{EQ.7}
$$

The less difference between input and output voltage, the higher efficiency it is. The minimum dropout voltage of LDO of ISL97646 is 300mV.

The ceramic capacitors are recommended for the LDO input and output capacitor. Larger capacitors help reduce noise and deviation during transient load change.

# *Gate Pulse Modulator Circuit*

The gate pulse modulator circuit functions as a three way multiplexer, switching VGHM between ground, VDD1 and VGH. Voltage selection is provided by digital inputs VDPM (enable) and VFLK (control). High to low delay and slew control is provided by external components on pins CE and RE, respectively. A block diagram of the gate pulse modulator circuit is shown in Figure [16](#page-11-0).

When VDPM is LOW, the block is disabled and VGHM is grounded. When VDPM is HIGH, the output is determined by VFLK. When VFLK goes high, VGHM is pulled to VGH by a 70 $\Omega$  switch. When VFLK goes low, there is a delay controlled by capacitor CE, following which VGHM is driven to VDD1, with a slew rate controlled by resistor RE. Note that VDD1 is used only as a reference voltage for an amplifier, thus does not have to source or sink a significant DC current.



<span id="page-11-0"></span>**FIGURE 16. GATE PULSE MODULATOR CIRCUIT BLOCK DIAGRAM**

Low to high transition is determined primarily by the switch resistance and the external capacitive load. High to low transition is more complex. Take the case where the block is already enabled (VDPM is H). When VFLK is H, pin CE is grounded. On the falling edge of VFLK, a current is passed into pin CE, to charge an external capacitor to 1.2V. This creates a delay, equal to CE\*4200. At this point, the output begins to pull down from VGH to VDD1. The slew current is equal to 300/(RE + 5000)\*Load Capacitance.



**FIGURE 17. GATE PULSE MODULATOR TIMING DIAGRAM**

#### *Start-Up Sequence*

Figure 18 shows a detailed start-up sequence waveform.





When  $V_{IN}$  exceeds 2.5V and ENABLE reaches the VIH threshold value, Boost converter and LDO start-up, and gate pulse modulator circuit output holds until VDPM goes to high. Note that there is a DC path in the boost converter from the input to the output through the inductor and diode, hence the input voltage will be seen at output with a forward voltage drop of diode before the part is enabled. If this voltage is not desired, the following circuit can be inserted between input and inductor to disconnect the DC path when the part is disabled.



#### **FIGURE 19. CIRCUIT TO DISCONNECT THE DC PATH OF BOOST CONVERTER**

# **V<sub>COM</sub>** Amplifier

The  $V_{COM}$  amplifier is designed to control the voltage on the back plate of an LCD display. This plate is capacitively coupled to the pixel drive voltage which alternately cycles positive and negative at the line rate for the display. Thus, the amplifier must be capable of sourcing and sinking capacitive pulses of current, which can occasionally be quite large (a few 100mA for typical applications).

The ISL97646  $V<sub>COM</sub>$  amplifier's output current is limited to 400mA. This limit level, which is roughly the same for sourcing and sinking, is included to maintain reliable operation of the part. It does not necessarily prevent a large temperature rise if the current is maintained. (In this case the whole chip may be shut down by the thermal trip to protect functionality). If the display occasionally demands current pulses higher than this limit, the reservoir capacitor will provide the excess and the amplifier will top the reservoir capacitor back up once the pulse has stopped. This will happen on the  $\mu s$  time scale in practical systems and for pulses 2 or 3 times the current limit, the  $V_{COM}$  voltage will have settled again before the next line is processed.

## *Fault Protection*

ISL97646 provides the overall fault protections including overcurrent protection and over-temperature protection.

An internal temperature sensor continuously monitors the die temperature. In the event that die temperature exceeds the thermal trip point, the device will shut down and disable itself. The upper and lower trip points are typically set to +140°C and +100°C, respectively.

## *Layout Recommendation*

The device's performance including efficiency, output noise, transient response and control loop stability is dramatically affected by the PCB layout. PCB layout is critical, especially at high switching frequency.

There are some general guidelines for layout:

- 1. Place the external power components (the input capacitors, output capacitors, boost inductor and output diodes, etc.) in close proximity to the device. Traces to these components should be kept as short and wide as possible to minimize parasitic inductance and resistance.
- 2. Place  $V_{IN}$  and VDD bypass capacitors close to the pins.
- 3. Reduce the loop area with large AC amplitudes and fast slew rate.
- 4. The feedback network should sense the output voltage directly from the point of load, and be as far away from LX node as possible.
- 5. The power ground (PGND) and signal ground (SGND) pins should be connected at only one point.
- 6. The exposed die plate, on the underneath of the package, should be soldered to an equivalent area of metal on the PCB. This contact area should have multiple via connections to the back of the PCB as well as connections to intermediate PCB layers, if available, to maximize thermal dissipation away from the IC.
- 7. To minimize the thermal resistance of the package when soldered to a multi-layer PCB, the amount of copper track and ground plane area connected to the exposed die plate should be maximized and spread out as far as possible from the IC. The bottom and top PCB areas especially should be maximized to allow thermal dissipation to the surrounding air.
- 8. A signal ground plane, separate from the power ground plane and connected to the power ground pins only at the exposed die plate, should be used for ground return connections for control circuit.
- 9. Minimize feedback input track lengths to avoid switching noise pick-up.

A demo board is available to illustrate the proper layout implementation.

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# **Package Outline Drawing**

## **L24.4x4D**

**24 LEAD QUAD FLAT NO-LEAD PLASTIC PACKAGE Rev 2, 10/06**



NOTES:

- Dimensions in ( ) for Reference Only. 1. Dimensions are in millimeters.
- 2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.
- 3. Unless otherwise specified, tolerance : Decimal  $\pm 0.05$
- between 0.15mm and 0.30mm from the terminal tip. 4. Dimension b applies to the metallized terminal and is measured
- 5. Tiebar shown (if present) is a non-functional feature.
- located within the zone indicated. The pin #1 indentifier may be The configuration of the pin #1 identifier is optional, but must be 6. either a mold or mark feature.